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November 2013

FCH76N60NF N-Channel SupreMOS[®] FRFET[®] MOSFET 600 V, 72.8 A, 38 mΩ

Features

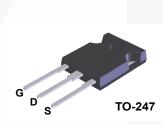
- R_{DS(on)} = 28.7 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 38 A
- Ultra Low Gate Charge (Typ. Q_g = 230 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 896 pF)
- 100% Avalanche Tested
- RoHS Compliant

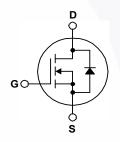
Application

- Solar Inverter
- AC-DC Power Supply

Description

The SupreMOS[®] MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest Rsp on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SupreMOS FRFET[®] MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

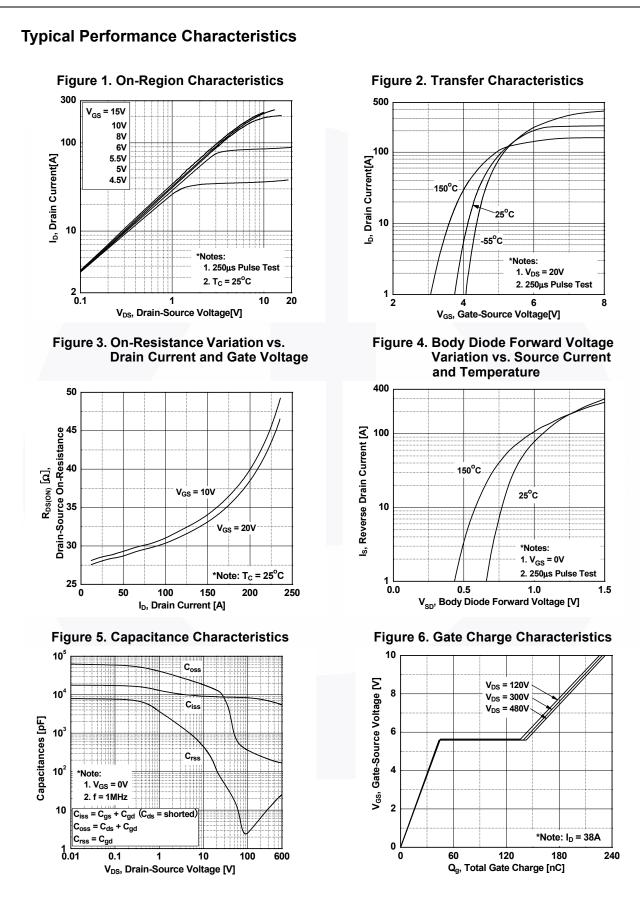
| Symbol | Parameter | | | FCH76N60NF | Unit |
|-----------------------------------|--|--|--------|-------------|-------------------|
| V _{DSS} | Drain to Source Voltage | | | 600 | V |
| V _{GSS} | Gate to Source Voltage | | | ±30 | V |
| ID | Drain Current | - Continuous (T _C = 25 ^o C) | | 72.8 | |
| | | - Continuous (T _C = 100 ^o C) | | 46 | Α |
| I _{DM} | Drain Current | - Pulsed (No | ote 1) | 218 | А |
| E _{AS} | Single Pulsed Avalanche Energy (Note 2) | | | 7381 | mJ |
| I _{AR} | Avalanche Current (Note 1) | | | 24.3 | А |
| E _{AR} | Repetitive Avalanche Energy (Note 1 | | ote 1) | 5.43 | mJ |
| -1/-14 | MOSFET dv/dt | | | 100 | V/ns |
| dv/dt | Peak Diode Recovery dv/dt (Note 3) | | | 50 | |
| P _D | Power Dissipation | (T _C = 25 ^o C) | | 543 | W |
| | | - Derate above 25°C | | 4.34 | W/ ^o C |
| T _J , T _{STG} | Operating and Storage Temperature Range | | | -55 to +150 | °C |
| TL | Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds | | S | 300 | °C |

Thermal Characteristics

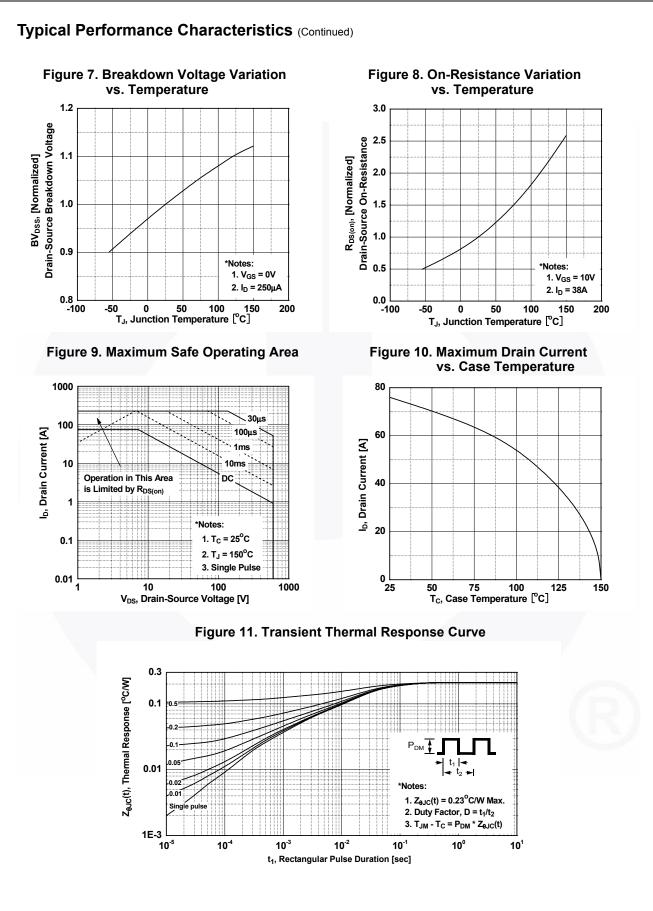
| Symbol | Symbol Parameter | | Unit |
|-----------------------|---|----|------|
| $R_{	extsf{	heta}JC}$ | C Thermal Resistance, Junction to Case, Max. | | °C/W |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction to Ambient, Max. | 40 | |

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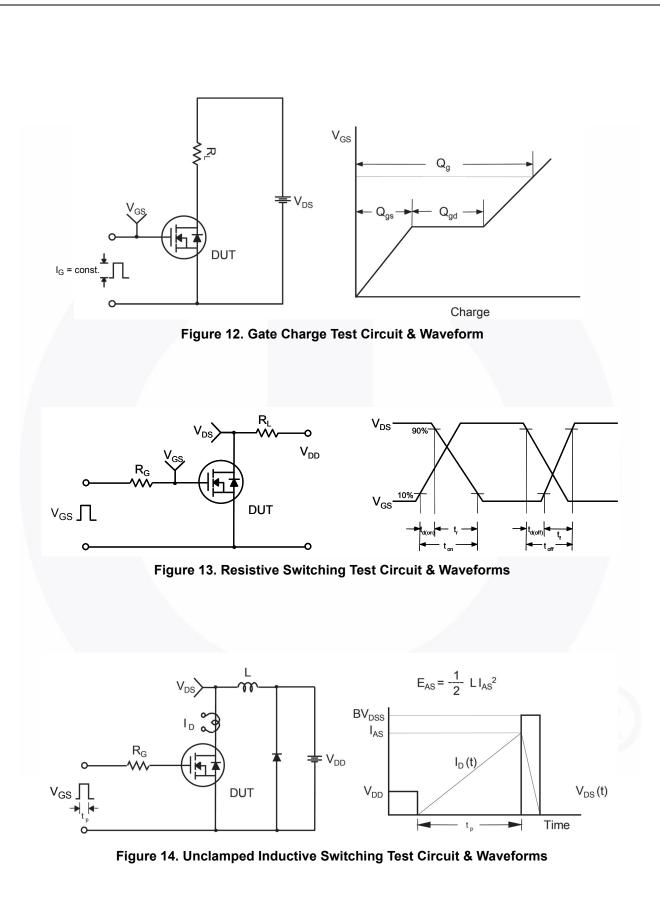
| Part Nur | nber | Top Mark | Package | Packing Method | Reel Size | • | Tape Width | Qu | antity | |
|---|--|---|---|---|-----------------------------------|------|------------|-------|----------|--|
| FCH76N | 60NF | FCH76N60NF | TO-247 | Tube | N/A | | N/A | 30 | units | |
| Electrica | l Chara | I cteristics T _c = 25°C u | nless other | wise noted. | | | | | | |
| Symbol | | Parameter | | Test Conditions | \$ | Min. | Тур. | Max. | Unit | |
| Off Charac | teristics | | | | | | | | | |
| BV _{DSS} | Drain to S | Source Breakdown Voltage | I _D = | 1 mA, V _{GS} = 0 V, T _C = | = 25°C | 600 | - | - | V | |
| ΔΒV _{DSS} / ΔΤ _J | Breakdow Coefficier | wn Voltage Temperature nt | I _D = | 1 mA, Referenced to | 25°C | - | 0.73 | - | V/ºC | |
| | Zero Gat | e Voltage Drain Current | | = 480 V, V_{GS} = 0 V | | - | - | 10 | | |
| IDSS | Zero Gat | e voltage Drain Guirent | | = 480 V, V_{GS} = 0 V, T | _C = 125 ^o C | - | - | 100 | μA | |
| I _{GSS} | Gate to E | Body Leakage Current | V _{GS} | $= \pm 30 \text{ V}, \text{ V}_{\text{DS}} = 0 \text{ V}$ | | - | - | ±100 | nA | |
| On Charac | teristics | | | | | | | | | |
| V _{GS(th)} | Gate Thr | eshold Voltage | V _{GS} | _s = V _{DS} , I _D = 250 μA | | 3.0 | - | 5.0 | V | |
| R _{DS(on)} | Static Dra | ain to Source On Resistance | | s = 10 V, I _D = 38 A | | - | 28.7 | 38.0 | mΩ | |
| 9 _{FS} | Forward | Transconductance | | = 20 V, I _D = 38 A | | - | 92 | - | S | |
| Dynamic C | horooto | riation | | | | | | | | |
| - | 1 | | | | | | 9205 | 11045 | ~ Г | |
| C _{iss} | Input Cap | | VDS | V _{DS} = 100 V, V _{GS} = 0 V f = 1 MHz | | - | 8305 | 11045 | pF | |
| C _{oss} | - | apacitance | | | | - | 361 | 480 | pF | |
| C _{rss} | | Transfer Capacitance | V | = 280 V V = 0 V f | | - | 3.3 192 | 5.0 | pF pF | |
| C _{oss} | | apacitance | - | $_{\rm S} = 380$ V, V _{GS} = 0V, f = | | - | 896 | - | pr pF | |
| C _{oss(eff.)} | | Output Capacitance e Charge at 10V | | $V_{DS} = 0 V \text{ to } 380 V, V_{GS} = 0 V$ $V_{DS} = 380 V, I_D = 38 A,$ $V_{GS} = 10 V$ (Note 4) | | - | 230 | - 300 | nC | |
| Q _{g(tot)} | | - | | | | - | 44 | 300 | nC | |
| Q _{gs} | - | Source Gate Charge | VGS | | | - | 95 | - | nC | |
| Q _{gd} ESR | | nt Series Resistance(G-S) | f _ / | 1 MHz | (11010-1) | - | 95 | - | Ω | |
| | · | | = | | | - | 1.2 | - | 52 | |
| Switching | | | | | | | | | | |
| t _{d(on)} | | Delay Time | N N | V_{DD} = 380 V, I _D = 38 A R _G = 4.7 Ω | | - | 51 | 112 | ns | |
| t _r | | Rise Time | 00 | | | - | 44 | 98 | ns | |
| t _{d(off)} | | Delay Time | | | | - | 213 | 436 | ns | |
| t _f | Turn-Off I | Fall Lime | | | (Note 4) | - | 43 | 96 | ns | |
| Drain-Sour | ce Diod | e Characteristics | | | | | | | | |
| I _S | Maximum Continuous Drain to Source Diode Forward Current | | | | | - | - | 76 | A | |
| I _{SM} | Maximum | Maximum Pulsed Drain to Source Diode F | | orward Current | | - | - | 228 | Α | |
| V _{SD} | Drain to S | Source Diode Forward Voltag | e V _{GS} = 0 V, I _{SD} = 38 A | | | - | - | 1.2 | V | |
| t _{rr} | Reverse I | Recovery Time | | $V_{GS} = 0 \text{ V}, \text{ I}_{SD} = 38 \text{ A}$ $d\text{I}_F/dt = 100 \text{ A}/\mu\text{s}$ | | - | 200 | - | ns | |
| Q _{rr} | Reverse I | Recovery Charge | dl _E /o | | | - | 1.8 | - | μC | |

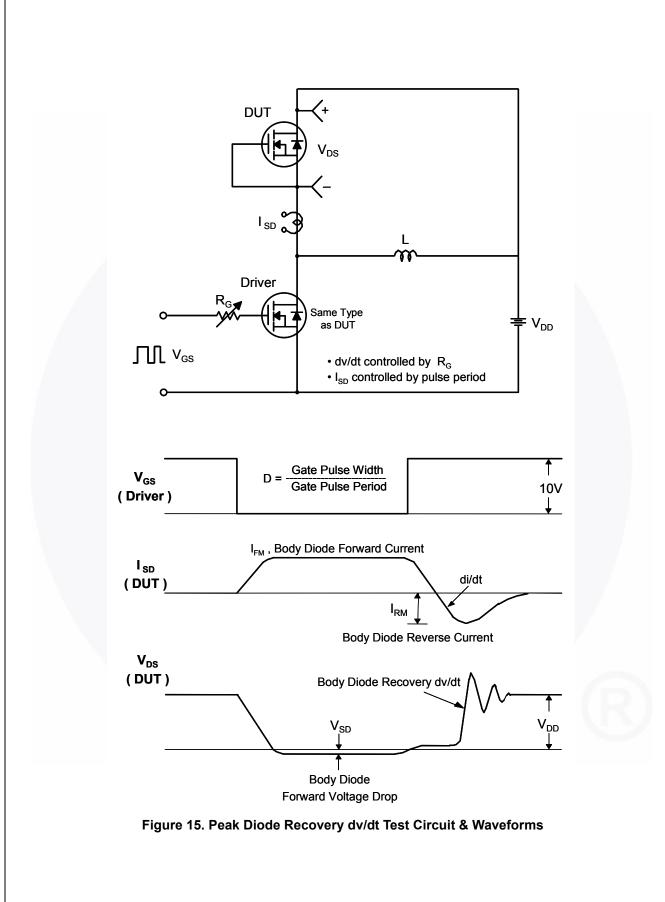


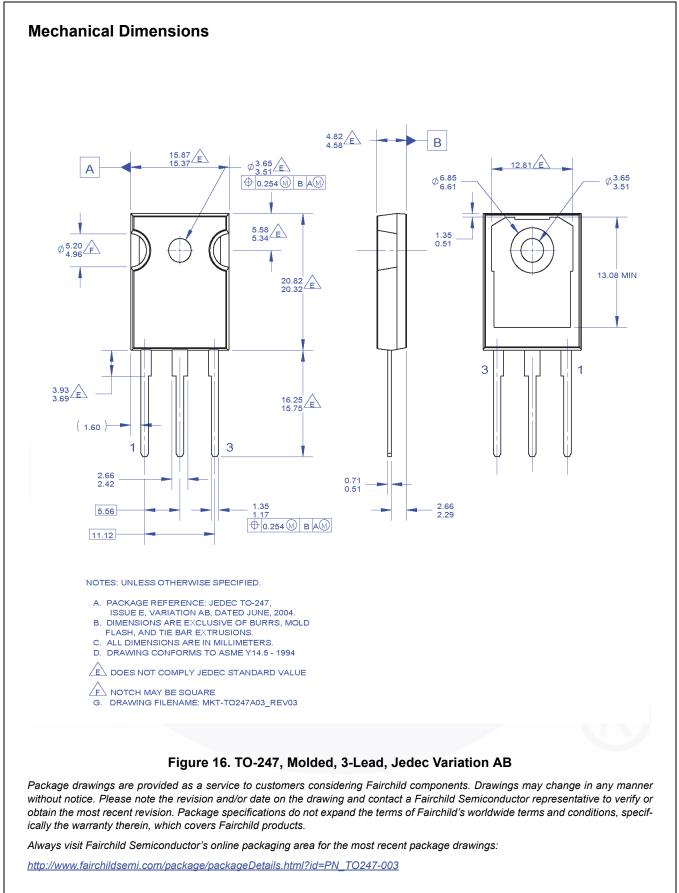
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FCH76N60NF — N-Channel SupreMOS[®] FRFET[®] MOSFET









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